UNR1231 (UN1231), UNR1231A (UN1231A)

Silicon NPN epitaxial planar type

For amplification of the low frequency

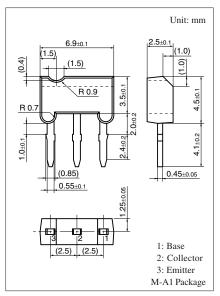
■ Features

- ullet High forward current transfer ratio h_{FE}
- M type mold package
- Costs can be reduced through downsizing of the equipment and reduction of the number of parts.

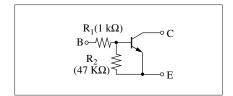
■ Absolute Maximum Ratings $T_a = 25$ °C

Paramete	Symbol	Rating	Unit	
Collector-base voltage	UNR1231	V _{CBO}	V _{CBO} 20	
(Emitter open)	UNR1231A		60	
Collector-emitter voltage	UNR1231	V _{CEO}	20	V
(Base open)	UNR1231A		50	
Collector current	I_C	0.7	A	
Peak collector current	I_{CP}	1.5	A	
Total power dissipation	P_{T}	1.0	W	
Junction temperature	T_{j}	150	°C	
Storage temperature	T_{stg}	-55 to +150	°C	

Note) *: Printed circuit board: Copper foil area of 1 cm² or more, and the board thickness of 1.7 mm for the collector portion



Internal Connection



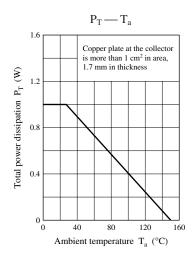
■ Electrical Characteristics $T_a = 25$ °C ± 3 °C

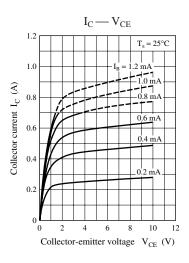
Parameter		Symbol	Conditions	Min	Тур	Max	Unit
Collector-base voltage	UNR1231	V_{CBO}	$I_C = 10 \ \mu A, I_E = 0$	20			V
(Emitter open)	UNR1231A			60			
Collector-emitter voltage	UNR1231	V _{CEO}	$I_C = 1 \text{ mA}, I_B = 0$	20			V
(Base open)	UNR1231A			50			
Collector-base cutoff curr	ent (Emitter open)	I_{CBO}	$V_{CB} = 15 \text{ V}, I_{E} = 0$			1	μΑ
Collector-emitter cutoff current (Base open)		I_{CEO}	$V_{CE} = 15 \text{ V}, I_{B} = 0$			10	μΑ
Emitter-base cutoff curren	nt (Collector open)	I_{EBO}	$V_{EB} = 14 \text{ V}, I_{C} = 0$			0.5	mA
Forward current transf	er ratio *	h_{FE}	$V_{CE} = 10 \text{ V}, I_{C} = 150 \text{ mA}$	800		2100	_
Collector-emitter satur	ation voltage *	V _{CE(sat)}	$I_C = 500 \text{ mA}, I_B = 5 \text{ mA}$			0.4	V
Transition frequency		f_T	$V_{CB} = 20 \text{ V}, I_E = -20 \text{ mA}, f = 200 \text{ MHz}$		55		MHz
Input resistance		R_1		0.7	1	1.3	V
Resistance ratio		R ₁ /R ₂		0.016	0.021	0.025	_

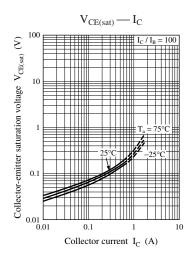
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

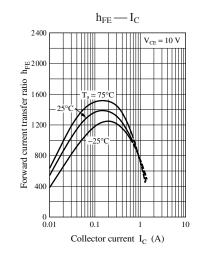
2. *: Pulse measurement

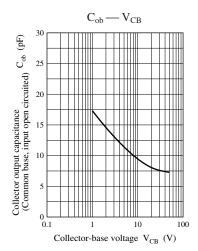
Note) The part numbers in the parenthesis show conventional part number.











2 SJH00005BED

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